



PRODUCT/PROCESS CHANGE NOTIFICATION

PCN IPG-DIS/14/8736
Dated 16 Oct 2014

Qualification of a second electrical wafer sort source for SiC diodes

Table 1. Change Implementation Schedule

Forecasted implementation date for change	09-Oct-2014
Forecasted availability date of samples for customer	09-Oct-2014
Forecasted date for STMicroelectronics change Qualification Plan results availability	09-Oct-2014
Estimated date of changed product first shipment	15-Jan-2015

Table 2. Change Identification

Product Identification (Product Family/Commercial Product)	SiC diodes
Type of change	Testing additional location
Reason for change	to increase our manufacturing capacity
Description of the change	Today ST inhouse plant located in Catania is qualified as EWS (Electrical Wafer Sorting) site for SiC Power schottky diode (STPSC). In Q4 2014, both ST Catania plant and ST Toa Payoh plant will be qualified as EWS site for all SiC Power schottky diode (STPSC)
Change Product Identification	internal codification and QA number
Manufacturing Location(s)	

Table 3. List of Attachments

Customer Part numbers list	
Qualification Plan results	



Customer Acknowledgement of Receipt	PCN IPG-DIS/14/8736					
Please sign and return to STMicroelectronics Sales Office	Dated 16 Oct 2014					
<input type="checkbox"/> Qualification Plan Denied <input type="checkbox"/> Qualification Plan Approved <input type="checkbox"/> Change Denied <input type="checkbox"/> Change Approved	<table border="1" style="width: 100%; border-collapse: collapse;"> <tr><td style="padding: 2px;">Name:</td></tr> <tr><td style="padding: 2px;">Title:</td></tr> <tr><td style="padding: 2px;">Company:</td></tr> <tr><td style="padding: 2px;">Date:</td></tr> <tr><td style="padding: 2px;">Signature:</td></tr> </table>	Name:	Title:	Company:	Date:	Signature:
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DOCUMENT APPROVAL

Name	Function
Paris, Eric	Marketing Manager
Duclos, Franck	Product Manager
Rebrasse, Jean-Paul	Q.A. Manager

PCN Product/Process Change Notification			
Qualification of a second electrical wafer sort source for SiC diodes			
Notification number:	IPG-DIS/14/8736	Issue Date	09/10/2014
Issued by	Aline AUGIS		
Product series affected by the change	STPSC1006D STPSC1006G-TR STPSC10H065B-TR STPSC10H065D STPSC10H065DI STPSC10H065DY STPSC10TH13TI STPSC1206D STPSC12H065CT STPSC12H065DY STPSC16H065CT STPSC2006CW STPSC20H065CT STPSC20H065CTY STPSC20H065CW STPSC20H065CWY STPSC40065CW STPSC406B-TR STPSC406D STPSC4H065B-TR STPSC4H065D STPSC4H065DI STPSC606D STPSC606G-TR STPSC6H065B-TR STPSC6H065D STPSC6H065DI STPSC6H065G-TR STPSC6H12B-TR1 STPSC6TH13TI STPSC806D STPSC806G-TR STPSC8H065B-TR STPSC8H065CT STPSC8H065D STPSC8H065DI STPSC8H065G-TR STPSC8TH13TI		
Type of change :	Additional electrical wafer sort source		
Description of the change			
<p>Today ST inhouse plant located in Catania is qualified as EWS (Electrical Wafer Sorting) site for SiC Power schottky diode (STPSC).</p> <p>In Q4 2014, both ST Catania plant and ST Toa Payoh plant will be qualified as EWS site for all SiC Power schottky diode (STPSC)</p>			

(1) IPG: Industrial & Power Group - ASD: Application Specific Device – IPAD™: Integrated Passive and Active Devices

Reason for change

This additional EWS site will increase our manufacturing capacity for a better service on the considered Power Rectifier devices.

Former versus changed product:

The changed products do not present modified electrical, dimensional or thermal parameters, leaving unchanged the current information published in the product datasheet

The Moisture Sensitivity Level of the part (according to the IPC/JEDEC JSTD-020D standard) remains unchanged. The footprint recommended by ST remains the same. There is no change in the packing modes and the standard delivery quantities either.

The products remain in full compliance with the ST ECOPACK@2 grade (“halogen-free”).

Disposition of former products

Non applicable

Marking and traceability

There is no change on the marking. The traceability is secured by an internal codification and the QA number.

Qualification complete date

Week 39-2014

Forecasted sample availability

Product family	Sub-family	Commercial part Number	Availability date
Rectifiers	STPSC serie 600V	STPSCx06xx	W48-2014
Rectifiers	STPSC serie 650V	STPSCxH065xx	W01-2015

Change implementation schedule

Sales types	Estimated production start	Estimated first shipments
STPSC series	W44-2014	W03-2015

Comments:

Customer’s feedback

Please contact your local ST sales representative or quality contact for requests concerning this change notification.

Absence of acknowledgement of this PCN within 30 days of receipt will constitute acceptance of the change

Absence of additional response within 90 days of receipt of this PCN will constitute acceptance of the change

Qualification program and results

QRP14126 Attached

Qualification Report

EWS capacity extension in Singapore – Power Schottky Silicon Carbide diodes

General Information	
Product Line	<i>Rectifiers</i>
Product Description	<i>Silicon Carbide diodes</i>
Product Group	<i>IPG</i>
Product division	<i>ASD & IPAD</i>
Package	<i>Multiple</i>
Maturity level step	<i>Qualified</i>

Locations	
Wafer fab	<i>ST Catania (ITALY)</i>
EWS plat	<i>ST Singapore</i>
Assembly plant	<i>ST Shenzhen (CHINA)</i>
Assessment	<i>PASS</i>

DOCUMENT INFORMATION

Version	Date	Pages	Prepared by	Approved by	Comment
Rev 1	10/09/2014	5	A. Dromel	JP Rebrasse	

Note: This report is a summary of the test trials performed in good faith by STMicroelectronics in order to evaluate the potential risks during the product life using a set of defined test methods.

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1 APPLICABLE AND REFERENCE DOCUMENTS

Document reference	Short description
JESD47-H	Stress-Test-Driven Qualification of Integrated Circuits
AEC Q101	Stress test qualification for automotive grade discrete semiconductors

2 GLOSSARY

SS	Sample Size
EWS	Electrical Wafer Sorting
TPY	Toa Payoh
AMK	Ang Mo Kio

3 EVALUATION OVERVIEW

3.1 Objectives

The objective of this report is to confirm that the new EWS test location in Toa Payoh has no impact on products and production flow.

The involved products are listed in the table below:

Product sub-Family	Product devices	
Silicon Carbide Power Schottky Rectifiers	STPSC1006D	STPSC406D
	STPSC1006G-TR	STPSC4H065B-TR
	STPSC10H065B-TR	STPSC4H065D
	STPSC10H065D	STPSC4H065DI
	STPSC10H065DI	STPSC606D
	STPSC10H065DY	STPSC606G-TR
	STPSC10H065G-TR	STPSC6C065D-L
	STPSC10TH13TI	STPSC6H065B-TR
	STPSC1206D	STPSC6H065D
	STPSC12C065D-L	STPSC6H065DI
	STPSC12H065CT	STPSC6H065G-TR
	STPSC12H065DY	STPSC6H12B-TR1
	STPSC16H065CT	STPSC6TH13TI
	STPSC2006CW	STPSC806D
	STPSC20H065CT	STPSC806G-TR
	STPSC20H065CTY	STPSC8H065B-TR
	STPSC20H065CW	STPSC8H065CT
	STPSC20H065CWY	STPSC8H065D
	STPSC40065CW	STPSC8H065DI
	STPSC406B-TR	STPSC8H065G-TR
	STPSC8TH13TI	

3.2 Conclusion

The flow study and comparative tests have shown that the devices will be tested exactly with same conditions with no impact on final electrical results.

4 CHANGE DESCRIPTION

The EWS testing flow remains identical in the new site, involving same equipment except inking prober as indicated in the table below. There is consequently no impact on the electrical parameters.

Description	Current	New
Wafer Fab	Italy Catania	Italy Catania
EWS Area	Italy Catania	Singapore Toa Payoh
EWS process flow	Test – SBL– Inking – QA Gate	Test – SBL– Inking – QA Gate
Tester	SPEA Tester (C430MX) + TEL P8 Prober	SPEA Tester (C430MX) + TEL P8 Prober
Test programs	SPEA test pgms using SPEA test function library (Multi-site)	SPEA test pgms using SPEA test function library (Multi-site)
Inking Prober	TEL P8XL	EG2001
Assembly and FT	Same flow	Same flow

5 TESTS RESULTS SUMMARY

5.1 Test vehicle

Lot #	Die code	Lot number	Wafer numbers
Lot1	MDC071Y4	Y342892	Wafer 01
Lot2	MDC071Y4	Y404986	Wafers 01 to 11
Lot3	MDC071Y4	Y404984	Wafers 01 & 02

5.2 Test plan and results summary

Lot # Wafer #	Mean comparison	CPK	Yields at EWS test in Catania	Yields at EWS test in Toa Pa Yoh	Acceptance criteria: yield $\Delta < 1\%$
Lot1	All parameters mean difference <2%	All parameters Cpk >2	97.1%	96.5%	Pass
Lot3 wafer 01	All parameters mean difference <2%	All parameters Cpk >2	96.7%	96.4%	Pass
Lot3 wafer 02	All parameters mean difference <2%	All parameters Cpk >2	97.3%	96.6%	Pass

Lot #	EWS flow at Toa Pa Yoh	CPK	Yields at EWS test in Toa Pa Yoh	Result
Lot2	Validated	All parameters Cpk >2 (*)	95.9%	Pass

(*) Exception Vf@1mA cpk>1.3

All Cpk of comparative measurements for datasheet parameters have revealed to be superior to 2, which warrants the full correlation between the testing results

Comparative yields have also proved to be fully correlated. Pareto defect and wafer maps have been studied carefully and compared. It appears that no major difference has been raised. Final test remains unchanged.

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